

POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	5 A
V_{RRM}	40 V
$T_j(\text{max})$	150°C
$V_F(\text{max})$	0.44 V

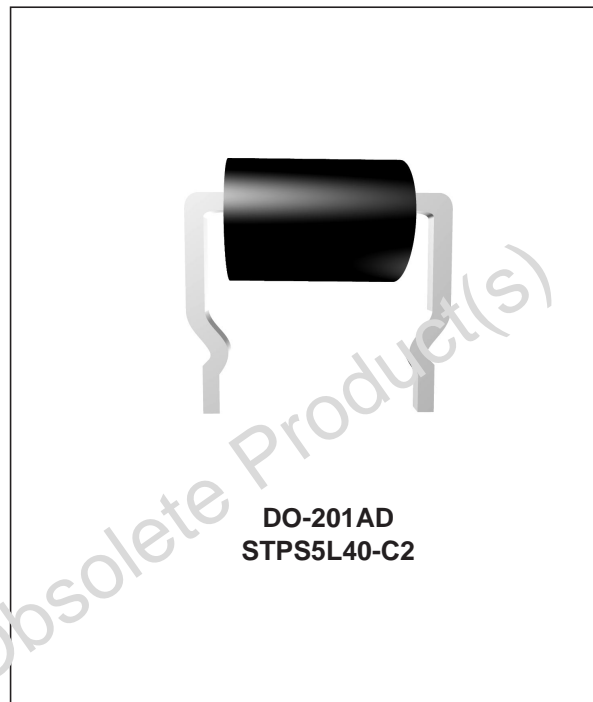
FEATURES AND BENEFITS

- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD VOLTAGE DROP FOR HIGHER EFFICIENCY.
- LOW THERMAL RESISTANCE
- AVALANCHE CAPABILITY SPECIFIED

DESCRIPTION

Axial Power Schottky rectifier suited for Switch Mode Power Supplies and high frequency inverters.

Packaged in DO-201AD, this device is intended for use in low voltage output for small battery chargers & consumer SMPS such as DVD and Set-Top-Box.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	40	V
$I_{F(RMS)}$	RMS forward current	15	A
$I_{F(AV)}$	Average forward current	5	A
I_{FSM}	Surge non repetitive forward current	150	A
P_{ARM}	Repetitive peak avalanche power	2700	W
T_{stg}	Storage temperature range	- 65 to + 150	°C
T_j	Maximum operating junction temperature *	150	°C
dV/dt	Critical rate of rise of reverse voltage (rated V_R , $T_j = 25^\circ\text{C}$)	10000	V/ μs

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

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THERMAL PARAMETERS

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to ambient	75	$^{\circ}\text{C}/\text{W}$
$R_{th(j-l)}$	Junction to leads	15	$^{\circ}\text{C}/\text{W}$
	Lead length = 10 mm		

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions	Min.	Typ.	Max.	Unit	
I_R^*	Reverse leakage current	$T_j = 25^{\circ}\text{C}$ $T_j = 100^{\circ}\text{C}$ $T_j = 125^{\circ}\text{C}$	$V_R = V_{RRM}$		0.2 8 25	mA	
V_F^*	Forward voltage drop	$T_j = 25^{\circ}\text{C}$ $T_j = 100^{\circ}\text{C}$ $T_j = 125^{\circ}\text{C}$	$I_F = 5\text{ A}$	0.44 0.40 0.38	0.50 0.46 0.44		V

Pulse test : * $t_p = 380\ \mu\text{s}$, $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation:

$$P = 0.34 \times I_{F(AV)} + 0.028 \times I_{F(RMS)}^2$$

Fig. 1: Conduction losses versus average current.

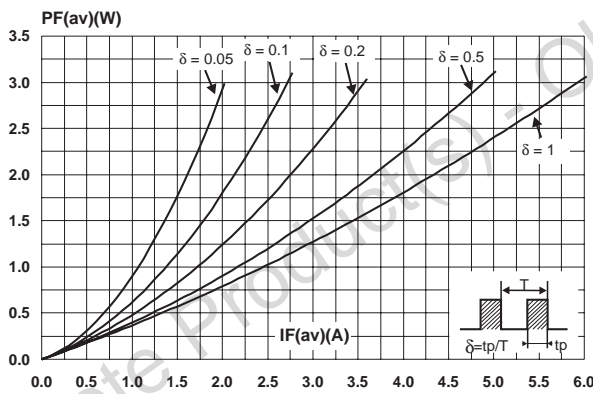


Fig. 3: Normalized avalanche power derating versus pulse duration.

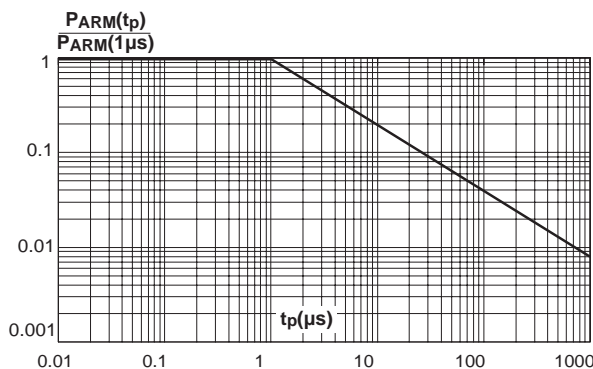


Fig. 2: Average forward current versus ambient temperature ($\delta = 0.5$).

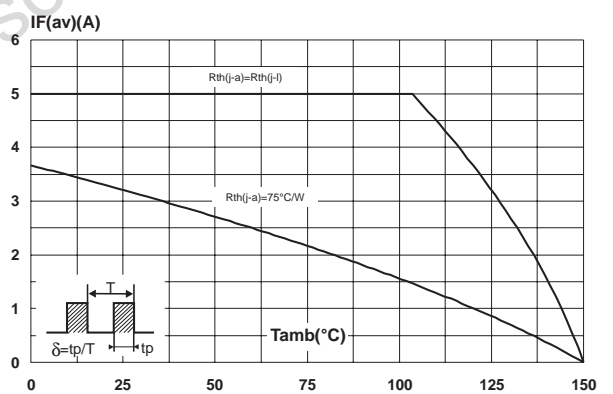


Fig. 4: Normalized avalanche power derating versus junction temperature.

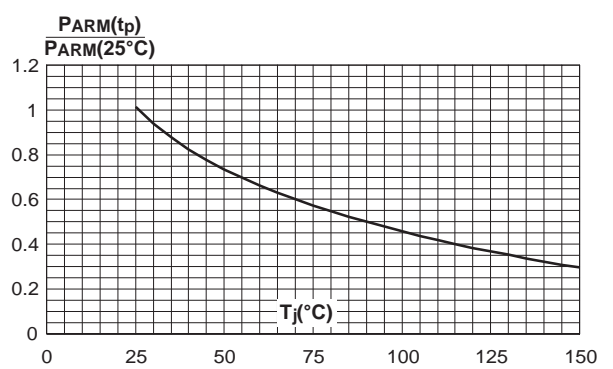


Fig. 5: Non repetitive surge peak forward current versus overload duration (maximum values).

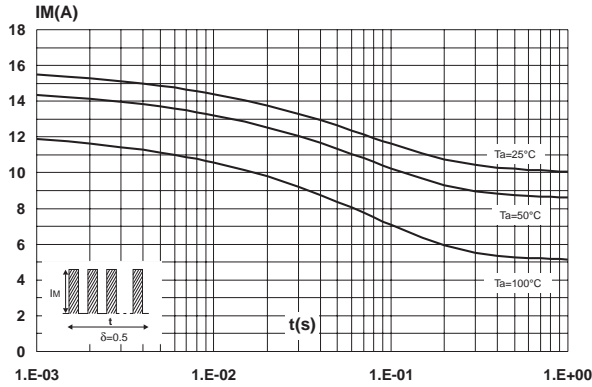


Fig. 6: Relative variation of thermal impedance junction to ambient versus pulse duration.

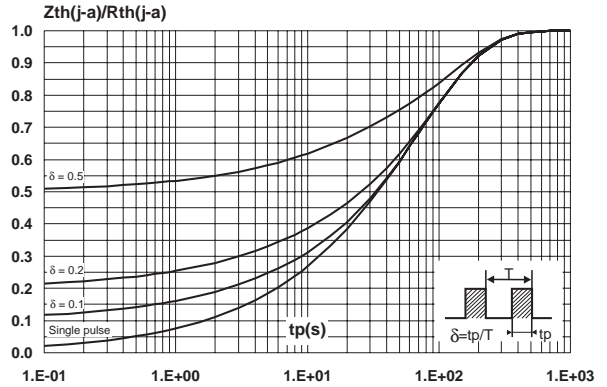


Fig. 7: Reverse leakage current versus reverse voltage applied (typical values).

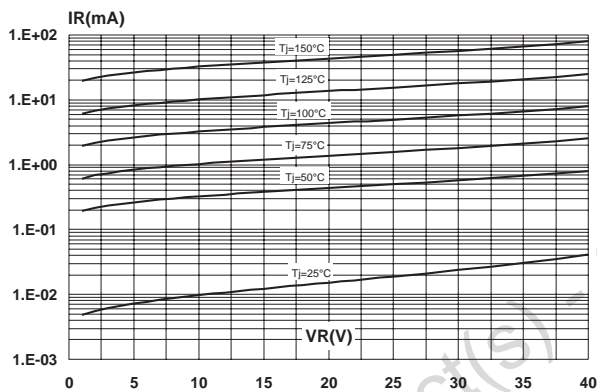


Fig. 8: Junction capacitance versus reverse voltage applied (typical values).

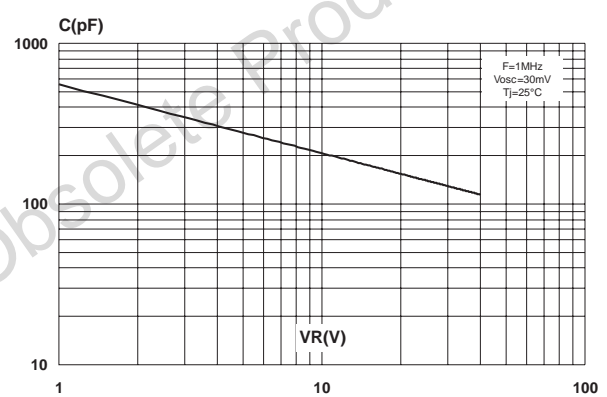


Fig. 9-1: Forward voltage drop versus forward current (low level).

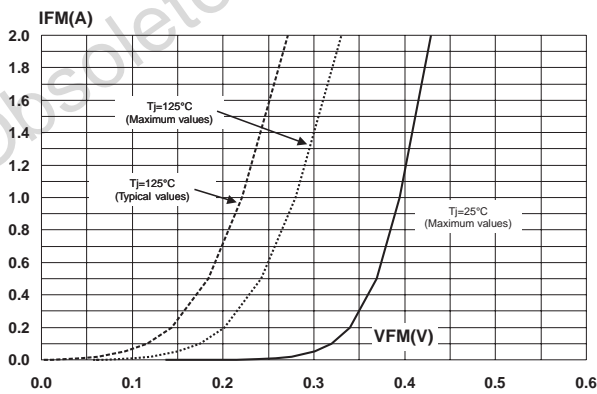
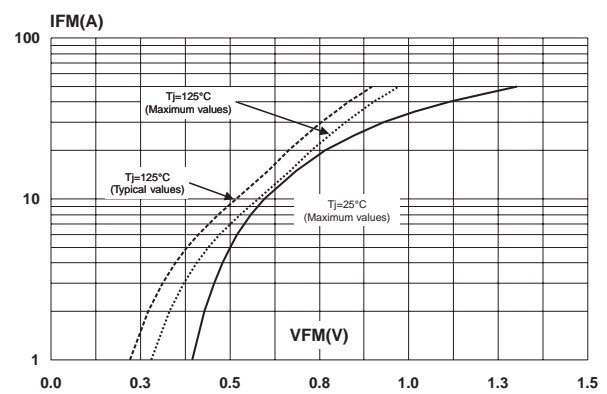


Fig. 9-2: Forward voltage drop versus forward current (high level).



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Fig. 10: Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed board FR4, Cu = 35µm).

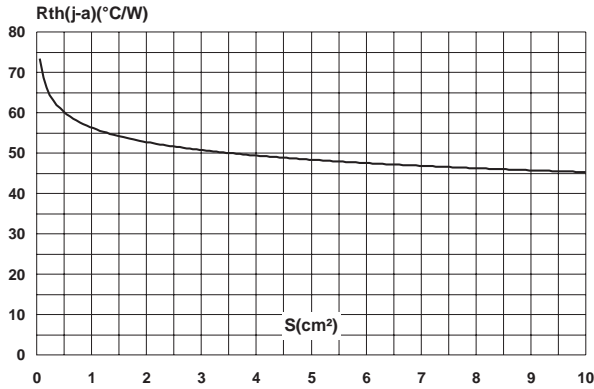
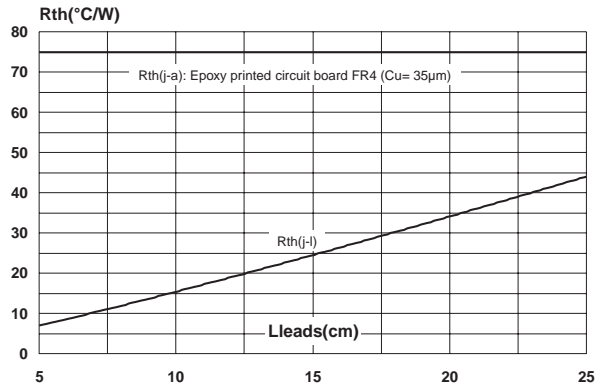
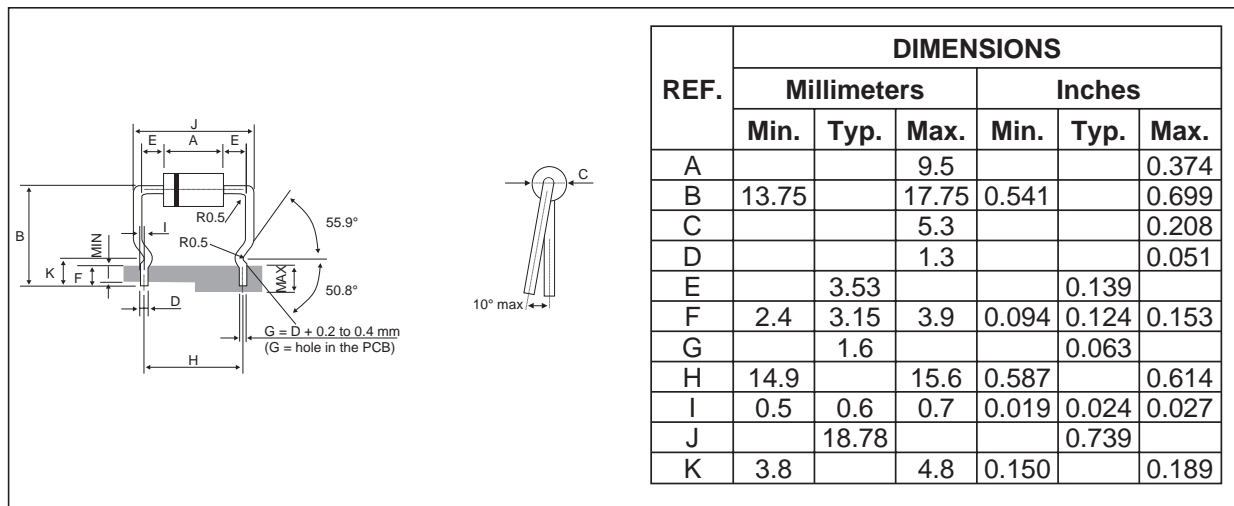


Fig. 11: Thermal resistances versus leads length.



PACKAGE MECHANICAL DATA DO-201AD plastic



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS5L40-C2	STPS5L40	DO-201AD	1.12g	500	Ammopack

- WHITE BAND INDICATES CATHODE
- EPOXY MEETS UL94,V0

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